

30A, 80V Schottky Barrier Rectifier

FEATURES

- AEC-Q101 qualified available
- Low power loss, high efficiency
- Guard ring for overvoltage protection
- High surge current capability
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

• Case: ITO-220AB

Molding compound meets UL 94V-0 flammability rating

• Terminal: Matte tin plated leads, solderable per J-STD-002

Mounting torque: 0.56 N·m maximum
Meet JESD 201 class 2 whisker test

• Polarity: As marked

• Weight: 1.70g (approximately)

| KEY PARAMETERS | | | | |
|--------------------|-----------|------|--|--|
| PARAMETER | VALUE | UNIT | | |
| I _F | 30 | Α | | |
| V_{RRM} | 80 | V | | |
| I _{FSM} | 200 | Α | | |
| T _{J MAX} | 150 | °C | | |
| Package | ITO-220AB | | | |
| Configuration | Dual dies | | | |

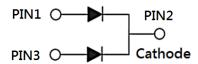








ITO-220AB



| ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted) | | | | |
|--|---------------------|-------------|------|--|
| PARAMETER | SYMBOL | MBRF3080CT | UNIT | |
| Marking code on the device | | MBRF3080CT | | |
| Repetitive peak reverse voltage | V _{RRM} | 80 | V | |
| Reverse voltage, total rms value | V _{R(RMS)} | 56 | V | |
| Forward current | I _F | 30 | Α | |
| Surge peak forward current, 8.3ms single half sine wave superimposed on rated load | I _{FSM} | 200 | А | |
| Peak repetitive reverse surge current ⁽¹⁾ | I _{RRM} | 0.5 | Α | |
| Critical rate of rise of off-state voltage | dv/dt | 10,000 | V/µs | |
| Junction temperature | T _J | -55 to +150 | °C | |
| Storage temperature | T _{STG} | -55 to +150 | °C | |

1

Notes:

1. $tp = 2.0\mu s$, 1.0KHz



MBRF3080CT Taiwan Semiconductor

| THERMAL PERFORMANCE | | | | | |
|-------------------------------------|------------------|-----|------|--|--|
| PARAMETER | SYMBOL | TYP | UNIT | | |
| Junction-to-case thermal resistance | R _{eJC} | 5 | °C/W | | |

| ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted) | | | | | |
|--|---|----------------|-----|------|------|
| PARAMETER | CONDITIONS | SYMBOL | TYP | MAX | UNIT |
| Forward voltage per diode ⁽¹⁾ | I _F = 15A,T _J = 25°C | V _F | - | 0.84 | V |
| | $I_F = 30A, T_J = 25^{\circ}C$ | | - | 0.94 | V |
| | I _F = 15A,T _J = 125°C | | - | 0.70 | V |
| | I _F = 30A,T _J = 125°C | | - | 0.82 | V |
| Reverse current @ rated V _R per diode ⁽²⁾ | T _J = 25°C | I _R | - | 200 | μΑ |
| | T _J = 125°C | | - | 10 | mA |

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

| ORDERING INFORMATION | | | | |
|------------------------------|-----------|-----------|--|--|
| ORDERING CODE ⁽¹⁾ | PACKAGE | PACKING | | |
| MBRF3080CT | ITO-220AB | 50 / Tube | | |
| MBRF3080CTH | ITO-220AB | 50 / Tube | | |

Notes:

1. "H" means AEC-Q101 qualified



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

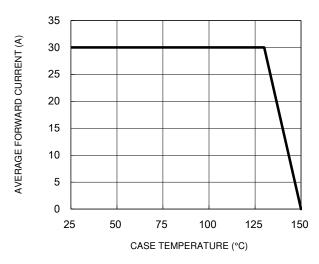


Fig.3 Typical Reverse Characteristics

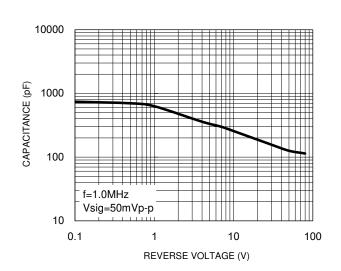
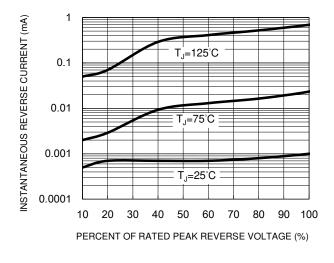


Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics



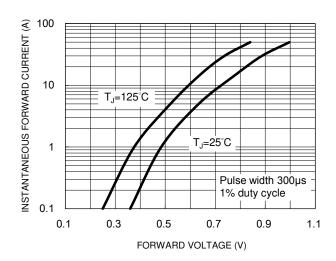
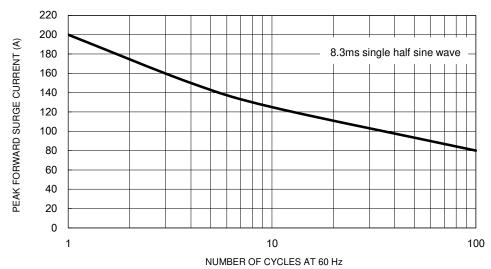


Fig.5 Maximum Non-Repetitive Forward Surge Current

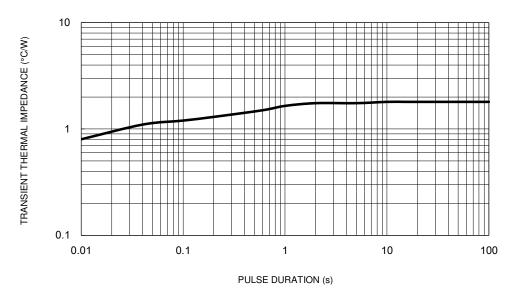


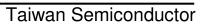


CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.6 Typical Transient Thermal Impedance

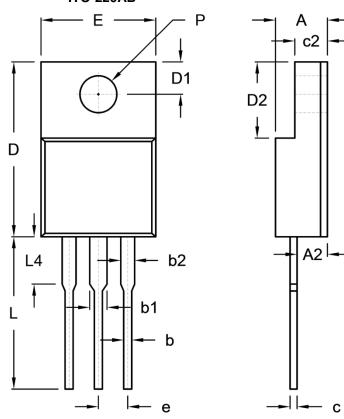






PACKAGE OUTLINE DIMENSIONS

ITO-220AB



| DIM. | Unit (mm) | | Unit (inch) | | |
|--------|-----------|-------|-------------|-------|--|
| Dilvi. | Min. | Max. | Min. | Max. | |
| Α | 4.30 | 4.70 | 0.169 | 0.185 | |
| A2 | 2.30 | 2.96 | 0.091 | 0.117 | |
| b | 0.50 | 0.90 | 0.020 | 0.035 | |
| b1 | - | 1.80 | - | 0.071 | |
| b2 | 0.95 | 1.45 | 0.037 | 0.057 | |
| С | 0.46 | 0.76 | 0.018 | 0.030 | |
| c2 | 2.50 | 3.16 | 0.098 | 0.124 | |
| D | 14.80 | 15.50 | 0.583 | 0.610 | |
| D1 | 2.40 | 3.20 | 0.094 | 0.126 | |
| D2 | 6.30 | 6.90 | 0.248 | 0.272 | |
| E | 9.60 | 10.30 | 0.378 | 0.406 | |
| е | 2.41 | 2.67 | 0.095 | 0.105 | |
| L | 12.60 | 13.80 | 0.496 | 0.543 | |
| L4 | - | 4.10 | - | 0.161 | |
| Р | 3.00 | 3.40 | 0.118 | 0.134 | |

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

YWW = Date Code F = Factory Code



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